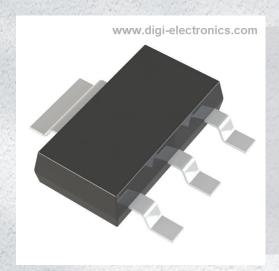


ZX5T955GTC Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number ZX5T955GTC-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number ZX5T955GTC

Description TRANS PNP 140V 4A SOT223-3

Detailed Description Bipolar (BJT) Transistor PNP 140 V 4 A 120MHz 3 W

Surface Mount SOT-223-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
ZX5T955GTC	Diodes Incorporated
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	4 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
140 V	360mV @ 300mA, 3A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
20nA (ICBO)	100 @ 1A, 5V
Power - Max:	Frequency - Transition:
3 W	120MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223-3
Base Product Number:	
ZX5T955	

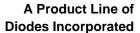
Environmental & Export classification

8541.29.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Affected	EAR99
HTSUS:	









140V PNP MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

Features

- BV_{CEO} > -140V
- I_C = -4A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -120mV @ I_C = -1A
- $R_{SAT} = 92m\Omega$ for a Low Equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Application

- Motor Driving
- Line Switching
- High Side Switches
- Subscriber Line Interface Cards (SLIC)

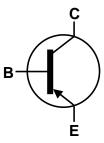
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

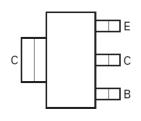
SOT223



Top View



Device Symbol



Top View Pin-Out

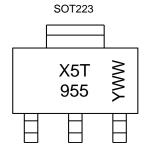
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T955GTA	X5T955	7	12	1,000
ZX5T955GTC	X5T955	13	12	4,000

Notes:

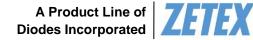
- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} \text{X5T 955} = \text{Product Type Marking Code} \\ \text{YWW} = \text{Date Code Marking} \\ \text{Y or } \overline{\text{Y}} = \text{Last Digit of Year (ex: 5= 2015)} \\ \text{WW or } \overline{\text{WW}} = \text{Week Code (01~53)} \\ \end{array}$







Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-180	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-4	Α
Peak Pulse Current	I _{CM}	-10	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	(Note 5)		3.0		
Power Dissipation	(Note 6)	P _D	2.0	W	
Power Dissipation	(Note 7)		1.6		
	(Note 8)		1.2	1	
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	62.5		
	(Note 7)		78.1	°C/W	
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	$R_{ hetaJL}$	10.5		
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 10)

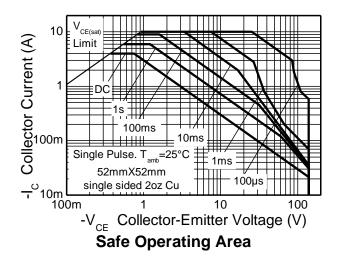
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

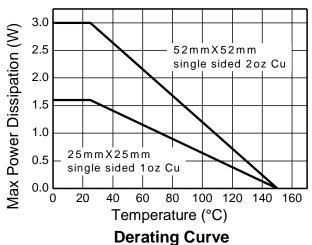
Notes:

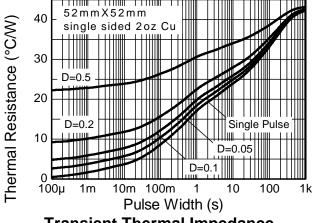
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

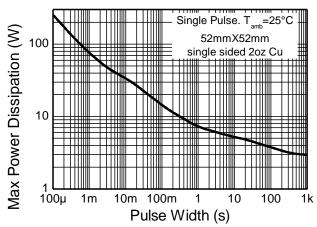


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-180	-200	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CER}	-180	-200	-	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-140	-160	-	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.3	-	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	-	< -1 -	-20 -500	nA nA	V _{CB} = -150V V _{CB} = -150V, T _A = +100°C
Collector Cut-Off Current	I _{CER} R≤1kΩ	-	< -1 -	-20 -500	nA nA	V _{CB} = -150V V _{CB} = -150V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}	-	< -1	-10	nA	V _{EB} = -6V
	h _{FE}	100	225	-	-	$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Transfer Static Ratio (Note 11)		100	200	300		$I_C = -1A$, $V_{CE} = -5V$
DC Current Transfer Static Ratio (Note 11)		45	100	-		$I_C = -3A$, $V_{CE} = -5V$
		-	5	-		$I_C = -10A$, $V_{CE} = -5V$
	V _{CE(sat)}	-	-40	-60	mV	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 11)		-	-55	-80		$I_C = -0.5A$, $I_B = -50mA$
Collector-Entitler Saturation Voltage (Note 11)		-	-85	-120		$I_C = -1A$, $I_B = -100mA$
		-	-275	-360		$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	-	-940	-1040	mV	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	-	-830	-930	mV	$I_C = -3A$, $V_{CE} = -5V$
Transitional Frequency (Note 11)	f _T	-	120	-	MHz	$I_C = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50 MHz
Output Capacitance	C_obo	-	33	-	pF	V _{CB} = -10V, f = 1MHz
Switching Time	toN	-	42	-	ns	V _{CC} = -50V, I _C = -1A,
Switching fille	t _{OFF}	-	636	-	115	$I_{B1} = -I_{B2} = -100 \text{mA}$

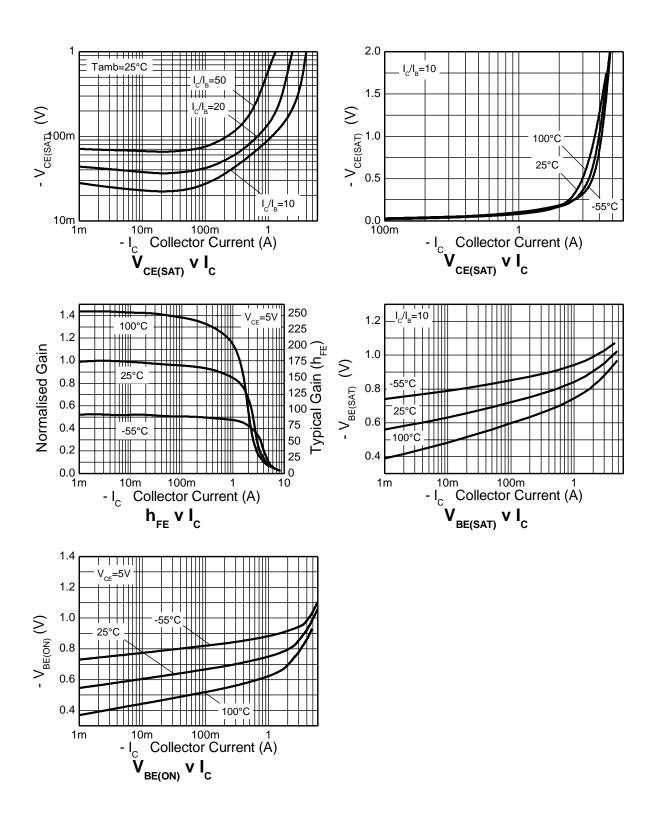
Note: 11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



May 2015

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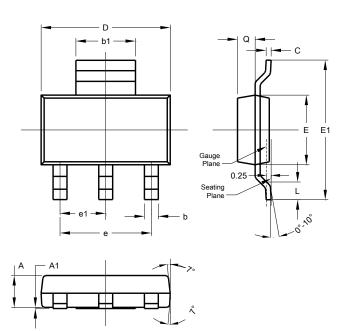
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

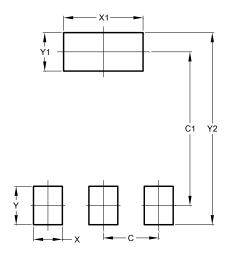
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

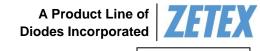
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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